

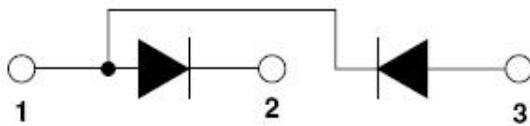
SM400T200D1 SCHOTTKY RECTIFIER



Features

- 175°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- UL approved file E517293
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings@T_J=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F(AV)}	50% duty cycle @T _C = 101°C, rectangular wave form	200(Per Leg) 400(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	2840	A
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH	15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A = 1.5 x V _R typical	1	A

Electrical Characteristics@T_J=25°C unless otherwise specified

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 200A, Pulse, T _J = 25 °C @ 400A, Pulse, T _J = 25 °C	0.90 1.02	0.99 1.15	V
	V _{F2}	@ 200A, Pulse, T _J = 125 °C @ 400A, Pulse, T _J = 125 °C	0.78 0.93	0.82 0.97	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.02	6	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	6	85	mA
Junction Capacitance(Per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	2870	5200	pF
Insulation Voltage	Visol	Ac. 50HZ; R.M.S; 1min	-	3000	V
		Ac. 50HZ; R.M.S; 1sec	-	3500	
Maximum voltage rate of change	dV/dt	Rated V _R	-	10000	V/μs

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications@T_J=25°C unless otherwise specified

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	T _J	-	-55 to +175		°C
Storage Temperature	T _{stg}	-	-55 to +175		°C
Maximum internal thermal resistance, junction to case per leg	R _{th(J-C)}	DC operation	0.32		°C/W
Typical thermal resistance, case to heatsink per module	R _{th(C-S)}	-	0.1		°C/W
Mounting Torque ± 15%	T _M	-	Mounting Torque(M6)	5	Nm
			Terminal Torque(M5)	4	
Module(Approximately)	Weight	-	100		g

Ratings and Characteristics Curves

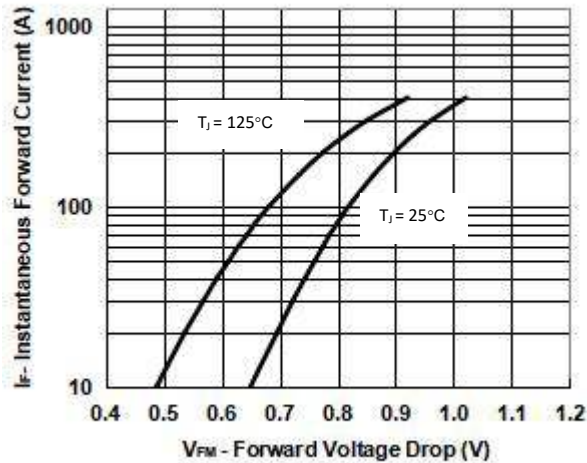


Fig. 1 - Typical Forward Characteristics

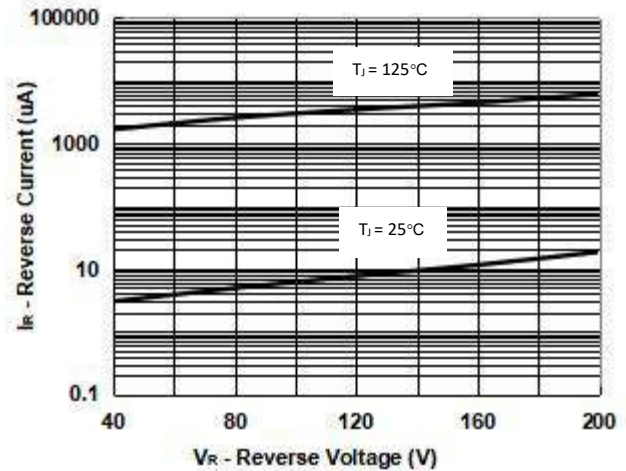


Fig. 2 - Typical Reverse Characteristics

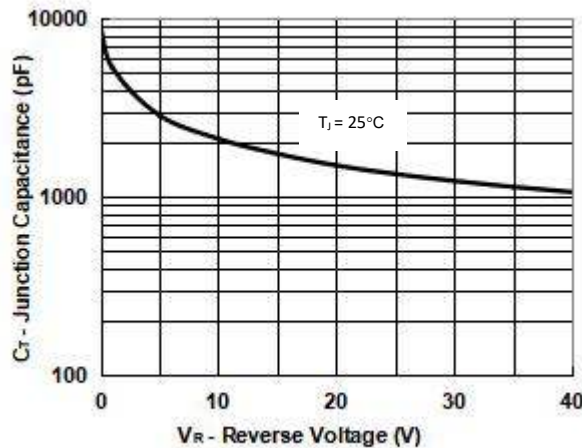


Fig. 3 - Typical Junction Capacitance

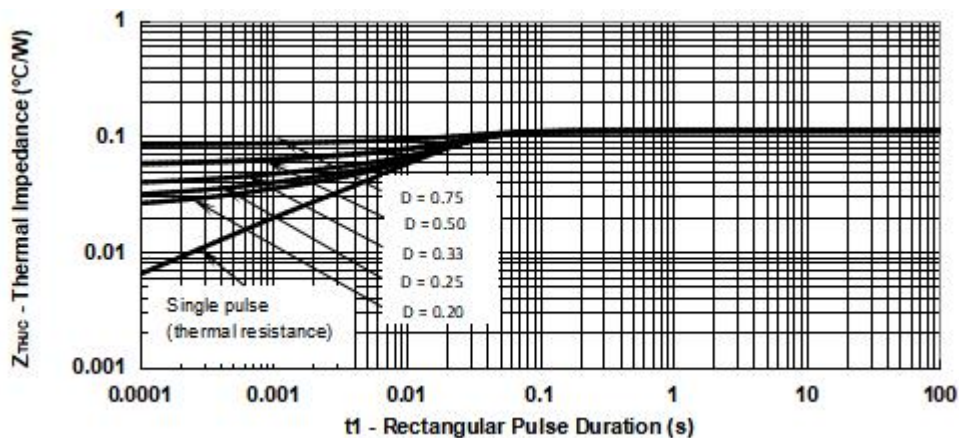


Fig. 4 Typical Thermal Impedance Z_{thJC} Characteristics (Per Leg)

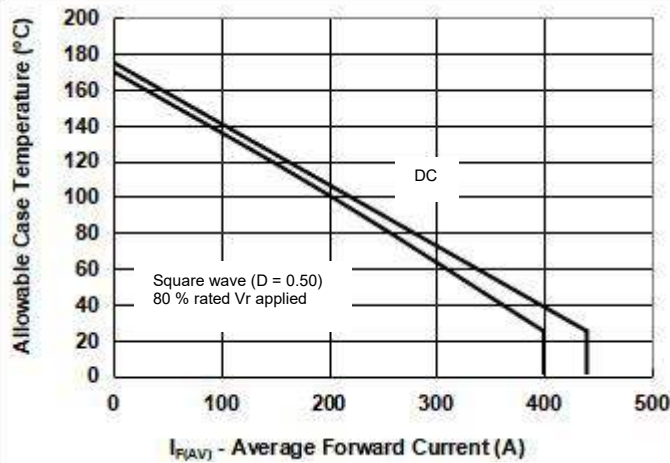


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

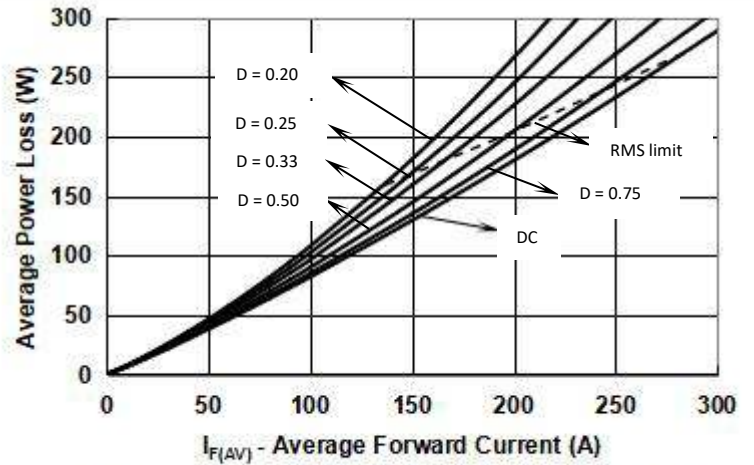


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

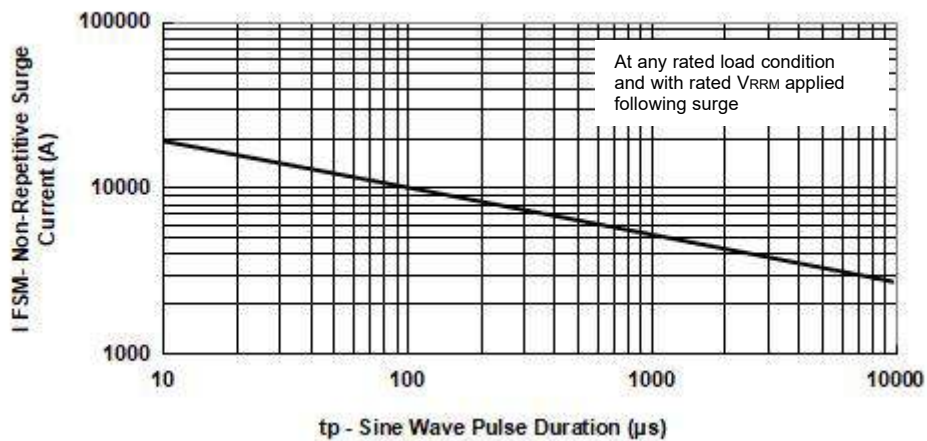
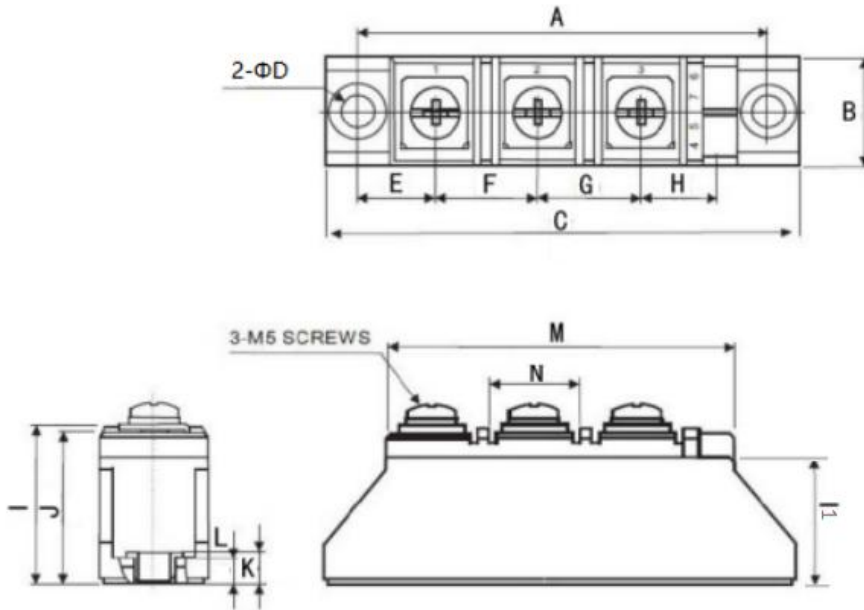


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

Mechanical Dimensions T1 (Millimeters)



SYMBOL	Millimeters	
	Min.	Max.
A	79.5	80.5
B	20.8	21.2
C	91.35	92.75
ΦD	6.1	6.5
E	14.5	15.5
F	19.5	20.5
G	19.5	20.5
H	14.5	15.5
I	30.5	31.5
I1	24	25
J	29	30
K	5.7	6.3
L	4.7	5.3
M	67.5	68.5
N	17.5	18.5

Ordering Information

Device	Package	Shipping
SM400T200D1	T1	14pcs/ box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXX is YYWW

SM400T200D1 = Part name
SS = SS
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

DISCLAIMER:

1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).

2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.

4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.

5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.

6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.

7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..